DATA SHEET

74LV373Octal D-type transparent latch (3-State)

Product specification Supersedes data of 1997 March 04 IC24 Data Handbook





Octal D-type transparent latch (3-State)

74LV373

FEATURES

- Wide operating voltage: 1.0 to 5.5V
- Optimized for Low Voltage applications: 1.0V to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Common 3-State output enable input
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV373 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC/HCT373.

The 74LV373 is an octal D-type transparent latch featuring separate D-type inputs for each latch and 3-State outputs for bus oriented applications. A latch enable (LE) input and an output enable (OE) input are common to all internal latches.

The '373' consists of eight D-type transparent latches with 3-State true outputs. When LE is HIGH, data at the Dn inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change each time its corresponding D-input changes.

When LE is LOW the latches store the information that was present at the D-inputs a set-up time preceding the HIGH-to-LOW transition of LE. When $\overline{\text{OE}}$ is LOW, the contents of the eight latches are available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the OE input does not affect the state of the latches.

The '373' is functionally identical to the '573', but the '573' has a different pin arrangement.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay D _n to Q _n LE to Q _n	C _L = 15pF V _{CC} = 3.3V	10 12	ns
C _I	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per latch	Notes 1, 2	22	pF

NOTES:

 f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$

2. The condition is $V_I = GND$ to V_{CC}

ORDERING AND PACKAGE INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic DIL	−40°C to +125°C	74LV373 N	74LV373 N	SOT146-1
20-Pin Plastic SO	−40°C to +125°C	74LV373 D	74LV373 D	SOT163-1
20-Pin Plastic SSOP Type II	−40°C to +125°C	74LV373 DB	74LV373 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV373 PW	74LV373PW DH	SOT360-1

PIN DESCRIPTION

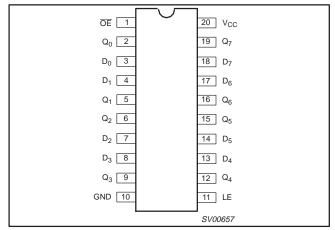
PIN NUMBER	SYMBOL	FUNCTION
1	ŌĒ	Output enabled input (active LOW)
2, 5, 6, 9, 12, 15, 16, 19	Q ₀ –Q ₇	3-State latch outputs
3, 4, 7, 8, 13, 14, 17, 18	D ₀ –D ₇	Data inputs
10	GND	Ground (0V)
11	LE	Latch enable input (active HIGH)
20	V _{CC}	Positive supply voltage

^{1.} C_{PD} is used to determine the dynamic power dissipation (P_D in μW) $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

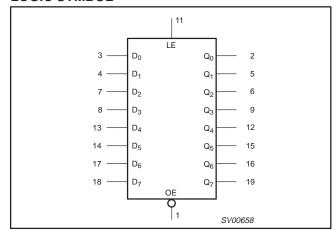
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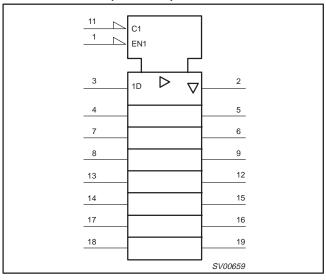
PIN CONFIGURATION



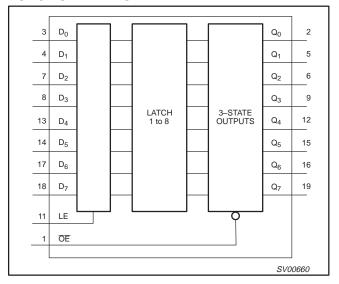
LOGIC SYMBOL



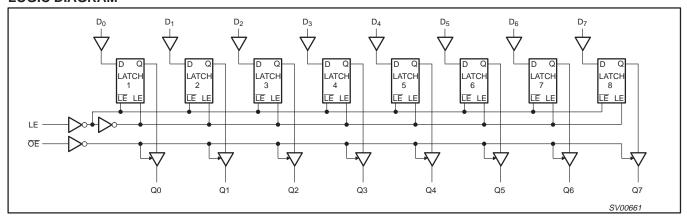
LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



LOGIC DIAGRAM



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FUNCTION TABLE

OPERATING MODES		INPUTS		INTERNAL	OUTPUTS Q ₀ to Q ₇ L H L	
OPERATING MODES	ŌĒ	LE	Dn	LATCHES	Q ₀ to Q ₇	
Enable and read register (transparent mode)	L	H	L	L	L	
	L	H	H	H	H	
Latch and read register	L	L	l	L	L	
	L	L	h	H	H	
Latch register and disable outputs	H	L	l	L	Z	
	H	L	h	H	Z	

H = HIGH voltage level

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note1	1.0	3.3	5.5	V
VI	Input voltage		0	-	V _{CC}	V
V _O	Output voltage		0	ı	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$ $V_{CC} = 3.6V \text{ to } 5.5V$	- - -	- - -	500 200 100 50	ns/V

NOTE:

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
±I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
±I _{OK}	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
±ΙΟ	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with –bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{tot}	Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition

L = LOW voltage level

I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition

X = Don't care

Z = High impedance OFF-state

^{1.} The LV is guaranteed to function down to $V_{CC} = 1.0V$ (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2V$ to $V_{CC} = 5.5V$.

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40)°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	
		V _{CC} = 1.2V	0.9			0.9		
V_{IH}	HIGH level Input	V _{CC} = 2.0V	1.4			1.4] ,
VIН	voltage	V _{CC} = 2.7 to 3.6V	2.0			2.0] `
		$V_{CC} = 4.5 \text{ to } 5.5 \text{V}$	0.7*V _{CC}			0.7*V _{CC}		
		V _{CC} = 1.2V			0.3		0.3	
V_{IL}	LOW level Input	V _{CC} = 2.0V			0.6		0.6	
۷IL	voltage	V _{CC} = 2.7 to 3.6V			0.8		0.8] `
		$V_{CC} = 4.5 \text{ to } 5.5$			0.3*V _{CC}		0.3*V _{CC}	<u> </u>
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$		1.2				
		$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	1.8	2.0		1.8]
	HIGH level output voltage; all outputs	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.5	2.7		2.5]
V_{OH}		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.8	3.0		2.8		V
0		$V_{CC} = 4.5V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	4.3	4.5		4.3]
	HIGH level output voltage; BUS driver	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 8\text{mA}$	2.40	2.82		2.20]
	outputs	$V_{CC} = 4.5V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 16mA$	3.60	4.20		3.50]
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0				
		$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2]
	LOW level output voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2]
V _{OL}		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2	V
02		$V_{CC} = 4.5V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2]
	LOW level output voltage; BUS driver	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 8mA$		0.20	0.40		0.50]
	outputs	$V_{CC} = 4.5V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 16$ mA		0.35	0.55		0.65]
I _I	Input leakage current	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 5.5V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND			5		10	μА
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 5.5V$; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μА
Δl _{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V \text{ to } 3.6V; V_I = V_{CC} - 0.6V$			500		850	μА

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NOTE:

^{1.} All typical values are measured at T_{amb} = 25°C.

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AC CHARACTERISTICS

 $\label{eq:gnd} \text{GND} = \text{OV}; \ t_\text{f} = t_\text{f} \leq \text{2.5ns}; \ C_\text{L} = \text{50pF}; \ R_\text{L} = 1 \text{K}\Omega$

	DL PARAMETER WAVEFO		CONDITION			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	CONDITION	_	40 to +85 °	C	-40 to	+125 °C	UNIT
		Ι Γ	V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
			1.2	_	65	-	-	-	
		Ī	2.0		22	37	-	48	
t _{PHL} /t _{PLH}	Propagation delay D _n to Q _n	Figure 1, 5	2.7	_	16	28	-	35	ns
	D _n to w _n	Ī	3.0 to 3.6		13 ²	22	-	28	
		Ι	4.5 to 5.5	_	-	16	-	20	
			1.2	_	80	-	-	-	
		Ι Γ	2.0		27	43	-	54	
t _{PHL} /t _{PLH}	Propagation delay LE to Q _n	Figure 2, 5	2.7	_	20	26	-	33	ns
	LL 10 Qn	l	3.0 to 3.6	_	15 ²	25	-	31	
		l	4.5 to 5.5	_	9.5 ³	19	-	24	
			1.2	_	80	-	-	T -	
	3-State output	Ι Γ	2.0		27	46	-	58	
t _{PZH} /t _{PZL}	enable time	Figure 3	2.7	_	20	28	-	35	ns
172H/172L 3	OE to Q _n		3.0 to 3.6	_	15 ²	27	-	34	
		l	4.5 to 5.5	_	-	23	-	29	
			1.2	_	75	-	-	T -	
	3-State output	l	2.0	_	27	46	-	58	
t _{PHZ} /t _{PLZ}	disable time	Figure 3	2.7	_	21	28	-	35	ns
	OE to Q _n	Ι Γ	3.0 to 3.6 – 16 ² 27		-	34	1		
			4.5 to 5.5	_	-	23	-	29	
			2.0	34	10	-	41	T -	
t _W	LE pulse width HIGH	Figure 2	2.7	25	8	-	30	<u> </u>	ns
			3.0 to 3.6	20	6 ²	-	24	T -	
			1.2	_	25	-	-	<u> </u>	
		l <u>.</u> [2.0	17	9	-	20	T -	
t _{su}	Setup time D _n to LE	Figure 4	2.7	13	6	-	15	-	ns
			3.0 to 3.6	10	5 ²	-	12	-	
			1.2	_	-15	-	_	-	
	11-11-1	-	2.0	5	- 5	-	5	-	
t _h	Hold time D _n to LE	Figure 4	2.7	5	-3	-	5	-	ns
			3.0 to 3.6	5	-3 ²	-	5	-	

All typical values are measured at T_{amb} = 25°C
 Typical values are measured at V_{CC} = 3.3V
 Typical values are measured at V_{CC} = 5.0V

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AC WAVEFORMS

 $V_M = 1.5V$ at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 V_{M} = 0.5V * V_{CC} at V_{CC} < 2.7V and \geq 4.5V

 $V_{\mbox{\scriptsize OL}}$ and $V_{\mbox{\scriptsize OH}}$ are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3V$ at $V_{CC} \ge 2.7V$ and $\le 3.6V$

 $V_X = V_{OL} + 0.1 V_{CC}$ at $V_{CC} < 2.7 V$ and $\geq 4.5 V$ $V_Y = V_{OH} - 0.3 V$ at $V_{CC} \geq 2.7 V$ and $\leq 3.6 V$

 $V_Y = V_{OH} - 0.1V_{CC}$ at $V_{CC} < 2.7V$ and $\geq 4.5V$

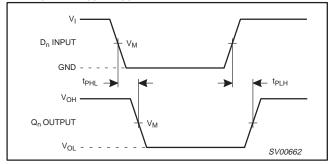


Figure 1. Data input (D_n) to output (Q_n) propagation delays and the output transition times.

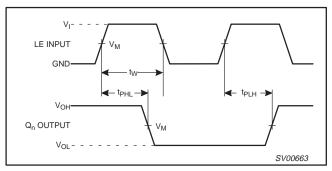


Figure 2. Latch enable input (LE) pulse width, the latch enable input to output (Qn) propagation delays and the output transition times.

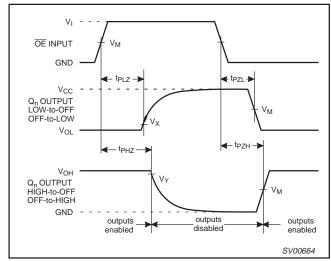


Figure 3. 3-State enable and disable times.

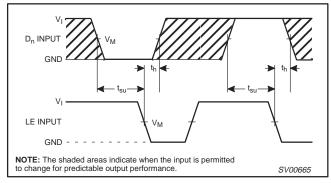


Figure 4. Data set-up and hold times for the D_n input to the LE input.

TEST CIRCUIT

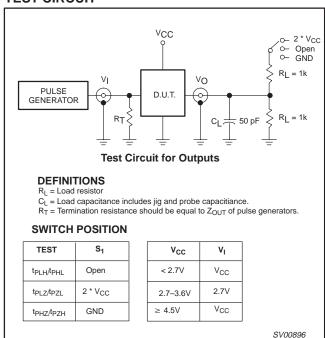
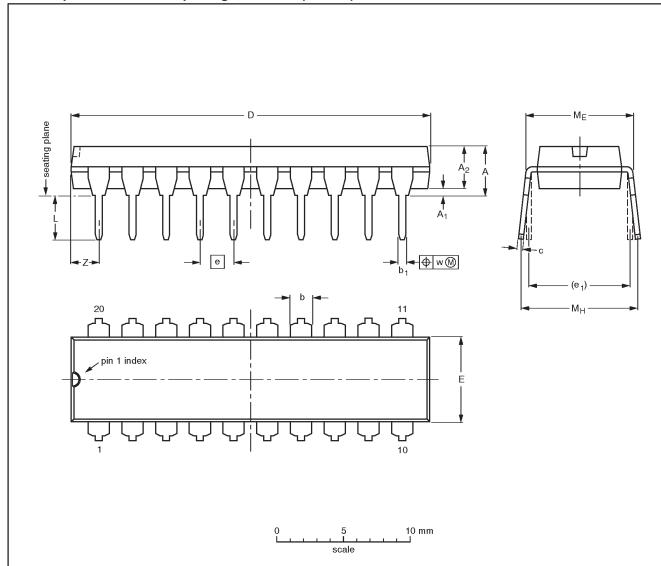


Figure 5. Load circuitry for switching times

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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

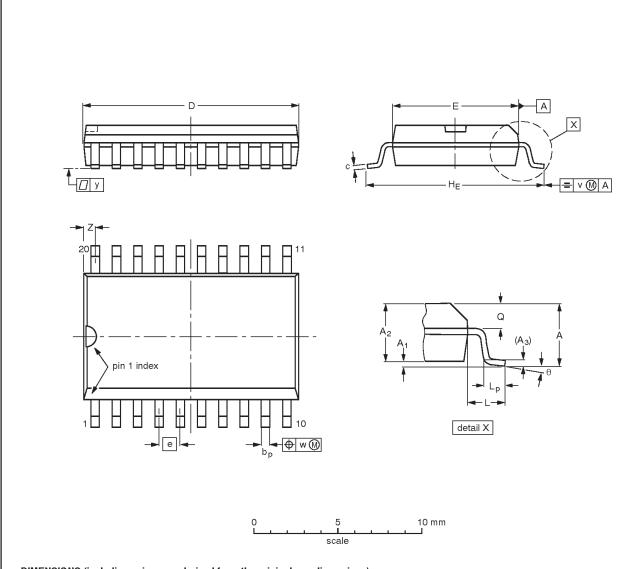
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT146-1			SC603		92-11-17 95-05-24

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	ø	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

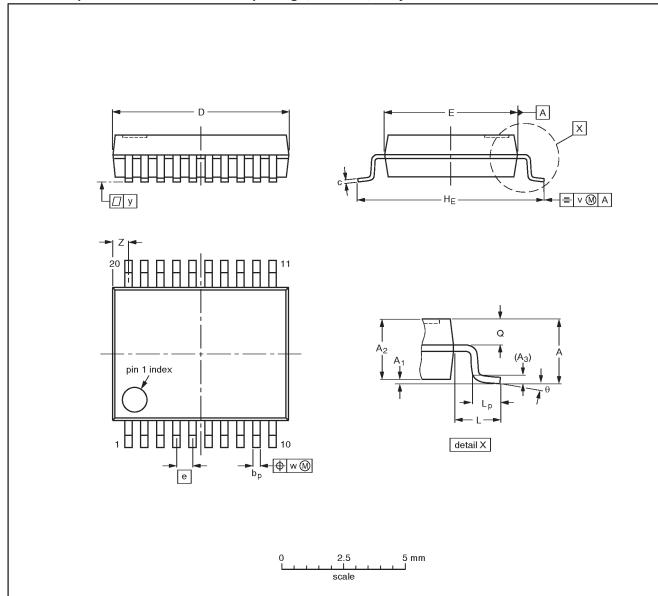
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT163-1	075E04	MS-013AC			-92-11-17 95-01-24

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

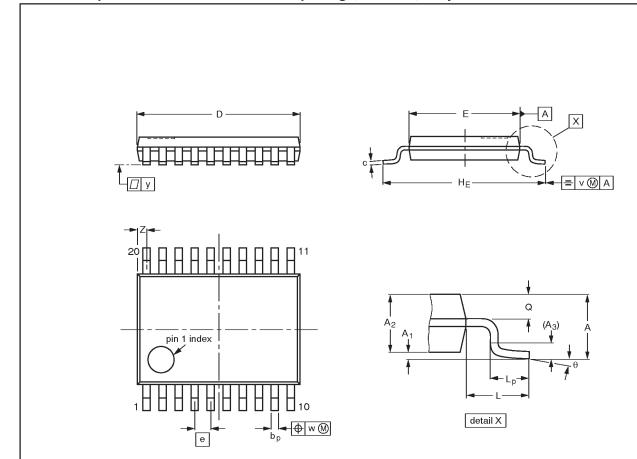
1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

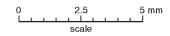
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
SOT339-1		MO-150AE				93-09-08 95-02-04	

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	рb	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT360-1		MO-153AC				-93-06-16 95-02-04

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	DEFINITIONS							
Data Sheet Identification	Product Status	Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.						
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Phillips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.						
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.						

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print code Date of release: 05-96

Document order number: 9397-750-04447

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